Darlington Complementary Silicon Power Transistors

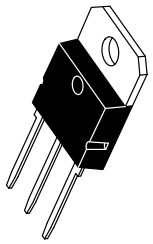
. . . designed for general–purpose amplifier and low frequency switching applications.

- High DC Current Gain — Min h_{FE} = 1000 @ I_C = 5 A, V_{CE} = 4 V
- Collector–Emitter Sustaining Voltage — @ 30 mA
  $V_{CEO(sus)}$ = 60 Vdc (Min) — TIP140, TIP145
  80 Vdc (Min) — TIP141, TIP146
  100 Vdc (Min) — TIP142, TIP147
- Monolithic Construction with Built–In Base–Emitter Shunt Resistor

NPN
TIP140
TIP141*
TIP142*
PNP
TIP145
TIP146*
TIP147*

***Motorola Preferred Device**

10 AMPERE DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS 60–100 VOLTS 125 WATTS



CASE 340D–02

MAXIMUM RATINGS

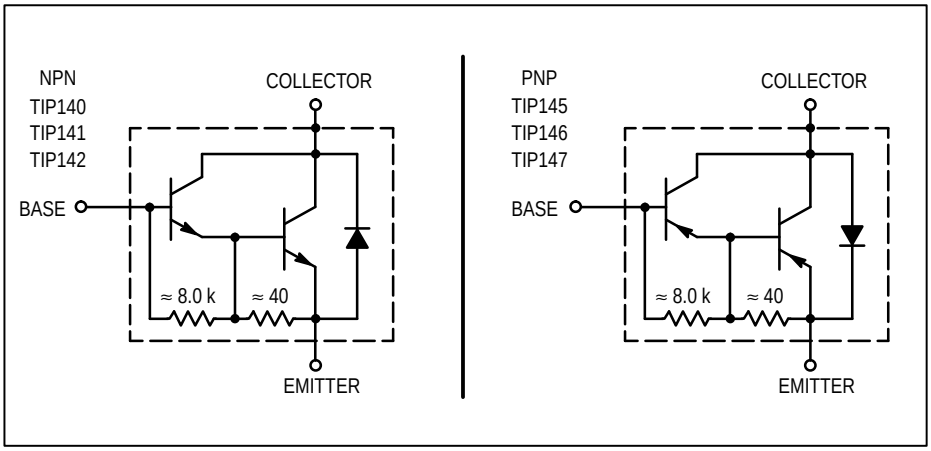
Rating	Symbol	TIP140 TIP145	TIP141 TIP146	TIP142 TIP147	Unit
Collector–Emitter Voltage	V_{CEO}	60	80	100	Vdc
Collector–Base Voltage	V_{CB}	60	80	100	Vdc
Emitter–Base Voltage	V_{EB}	5.0			Vdc
Collector Current — Continuous Peak (1)	I_C	10 15			Adc
Base Current — Continuous	I_B	0.5			Adc
Total Device Dissipation @ T_C = 25°C	P_D	125			Watts
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–65 to +150			°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.0	°C/W
Thermal Resistance, Case to Ambient	$R_{\theta JA}$	35.7	°C/W

(1) 5 ms, ≤ 10% Duty Cycle.

DARLINGTON SCHEMATICS



Preferred devices are Motorola recommended choices for future use and best overall value.

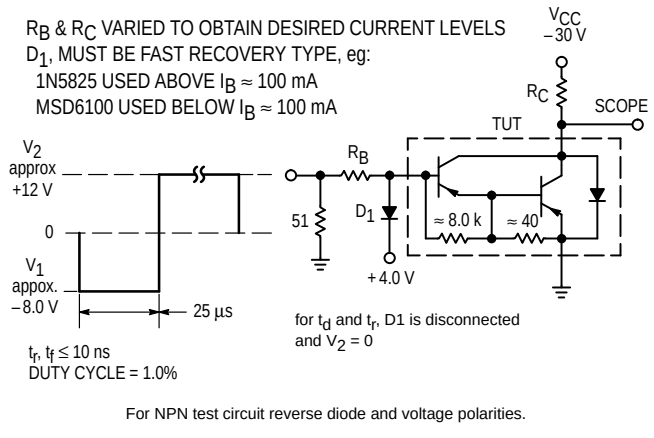
REV 1

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage (1)		$V_{CEO(sus)}$				Vdc
(I_C = 30 mA, I_B = 0)	TIP140, TIP145		60	—	—	
	TIP141, TIP146		80	—	—	
	TIP142, TIP147		100	—	—	
Collector Cutoff Current		I_{CEO}				mA
(V_{CE} = 30 Vdc, I_B = 0)	TIP140, TIP145		—	—	2.0	
(V_{CE} = 40 Vdc, I_B = 0)	TIP141, TIP146		—	—	2.0	
(V_{CE} = 50 Vdc, I_B = 0)	TIP142, TIP147		—	—	2.0	
Collector Cutoff Current		I_{CBO}				mA
(V_{CB} = 60 V, I_E = 0)	TIP140, TIP145		—	—	1.0	
(V_{CB} = 80 V, I_E = 0)	TIP141, TIP146		—	—	1.0	
(V_{CB} = 100 V, I_E = 0)	TIP142, TIP147		—	—	1.0	
Emitter Cutoff Current (V_{BE} = 5.0 V)		I_{EBO}	—	—	2 0	mA
ON CHARACTERISTICS (1)						
DC Current Gain		h_{FE}				—
(I_C = 5.0 A, V_{CE} = 4.0 V)			1000	—	—	
(I_C = 10 A, V_{CE} = 4.0 V)			500	—	—	
Collector–Emitter Saturation Voltage		$V_{CE(sat)}$				Vdc
(I_C = 5.0 A, I_B = 10 mA)			—	—	2.0	
(I_C = 10 A, I_B = 40 mA)			—	—	3.0	
Base–Emitter Saturation Voltage		$V_{BE(sat)}$	—	—	3.5	Vdc
(I_C = 10 A, I_B = 40 mA)						
Base–Emitter On Voltage		$V_{BE(on)}$	—	—	3.0	Vdc
(I_C = 10 A, V_{CE} = 4.0 Vdc)						
SWITCHING CHARACTERISTICS						
Resistive Load (See Figure 1)						
Delay Time	(V_{CC} = 30 V, I_C = 5.0 A, I_B = 20 mA, Duty Cycle ≤ 2.0%, I_{B1} = I_{B2}, R_C & R_B Varied, T_J = 25°C)	t_d	—	0.15	—	µs
Rise Time		t_r	—	0.55	—	µs
Storage Time		t_s	—	2.5	—	µs
Fall Time		t_f	—	2.5	—	µs

(1) Pulse Test: Pulse Width = 300 µs, Duty Cycle ≤ 2.0%.



For NPN test circuit reverse diode and voltage polarities.

Figure 1. Switching Times Test Circuit

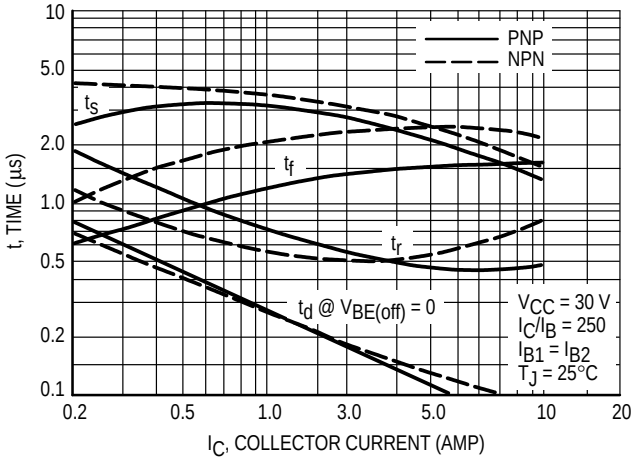
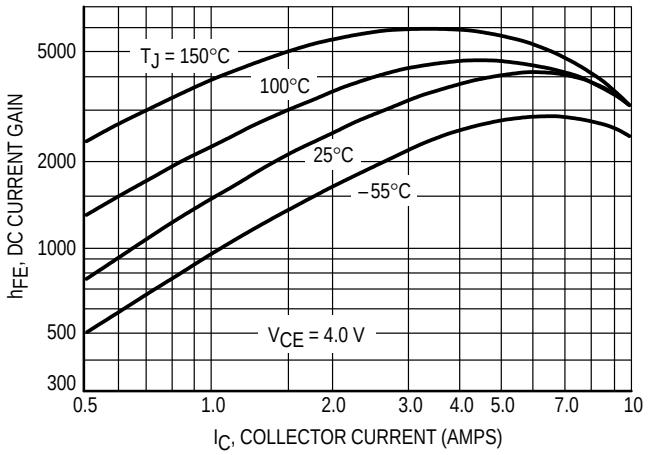


Figure 2. Switching Times

TYPICAL CHARACTERISTICS

NPN
TIP140, TIP141, TIP142



PNP
TIP145, TIP146, TIP147

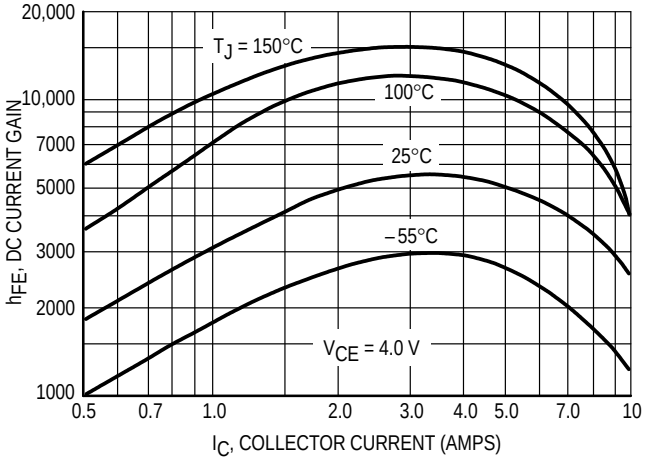
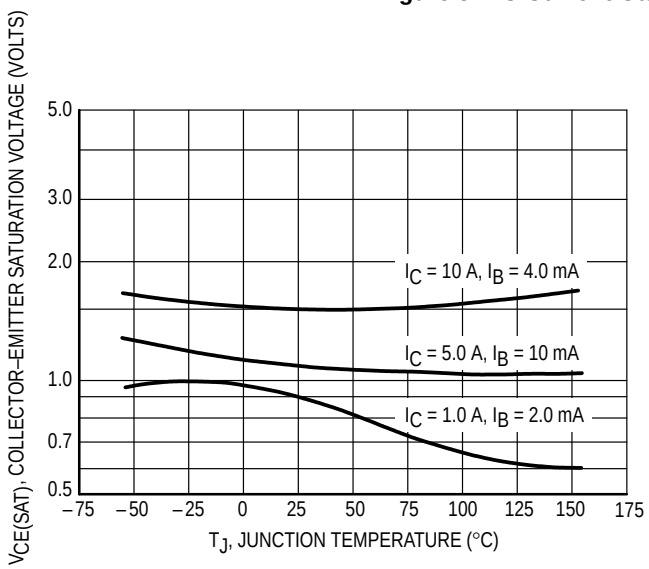


Figure 3. DC Current Gain versus Collector Current



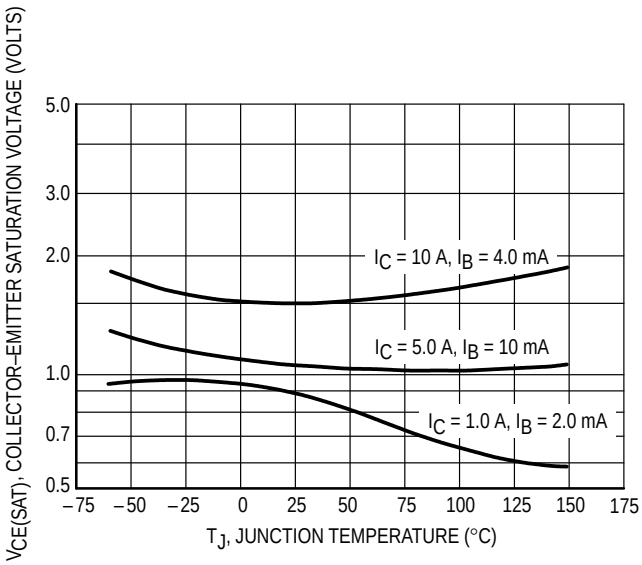
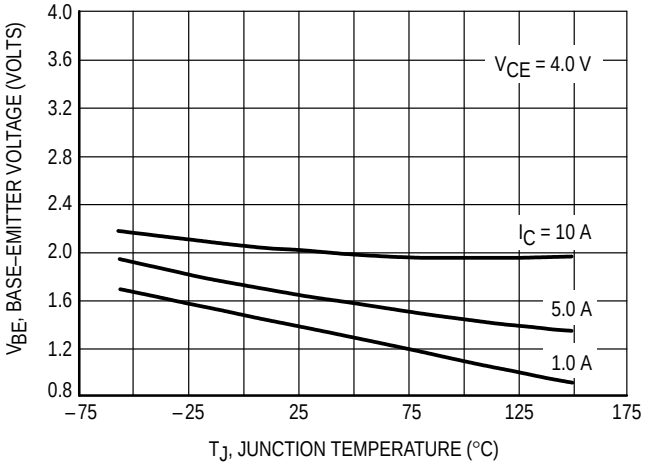


Figure 4. Collector–Emitter Saturation Voltage



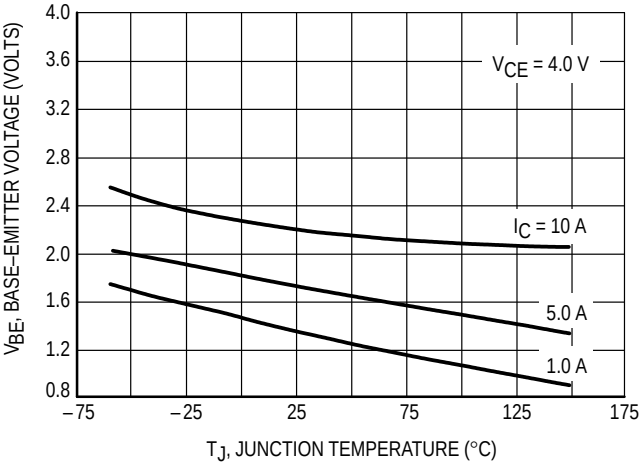


Figure 5. Base–Emitter Voltage

ACTIVE–REGION SAFE OPERATING AREA

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_{J(pk)}$ = 150°C; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

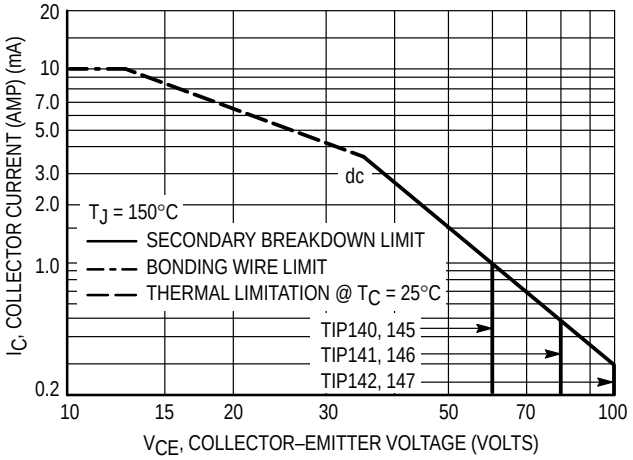


Figure 6. Active–Region Safe Operating Area

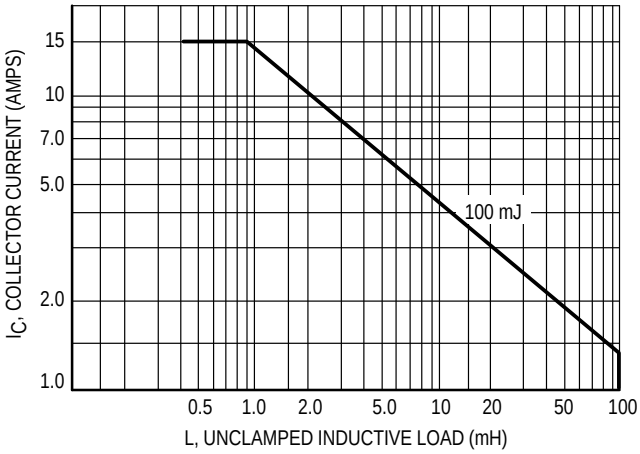
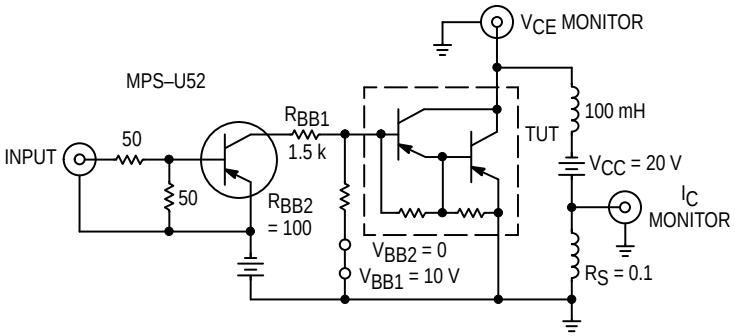
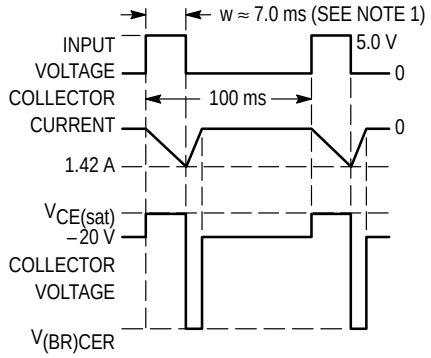


Figure 7. Unclamped Inductive Load



TEST CIRCUIT



VOLTAGE AND CURRENT WAVEFORMS

NOTE 1: Input pulse width is increased until I_{CM} = 1.42 A.
NOTE 2: For NPN test circuit reverse polarities.

Figure 8. Inductive Load

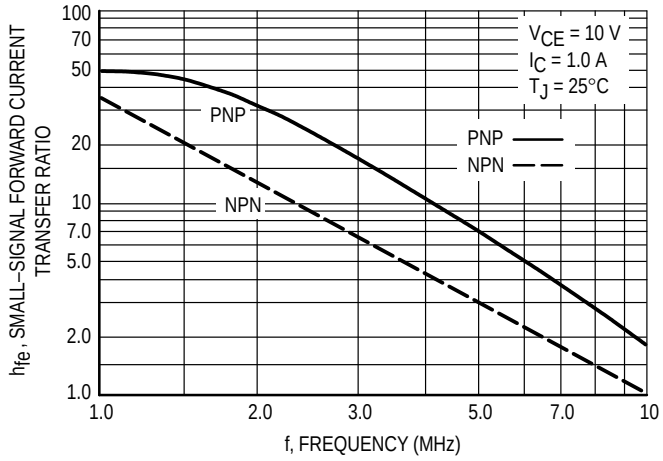


Figure 9. Magnitude of Common Emitter Small–Signal Short–Circuit Forward Current Transfer Ratio

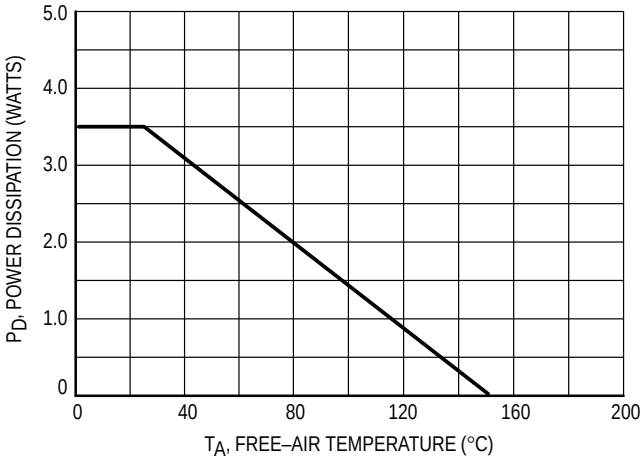
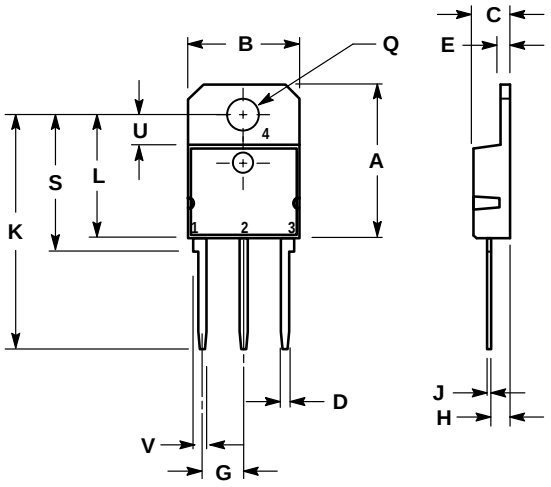


Figure 10. Free–Air Temperature Power Derating

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	—	20.35	—	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	—	16.20	—	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

CASE 340D–02
ISSUE B

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